

Renesas RA Family

QE for BLE Usage for IAR EWARM

Introduction

This document explains how to generate QE BLE code in e² studio and copy the generated code to IAR EW for ARM for Renesas RA Microcontrollers.

Target Device

EK-RA4W1 Evaluation Kit for RA4W1 group

Operating Environment

IDE	IAR Embedded Workbench for Arm version 9.20.2 or later e ² studio version 2021-10 is used for BLE Custom Profile creation and code generation
Configuration Tool	Smart Configurator (RA SC) v2021-10 and FSP v3.5.0
Toolchains	GNU Arm Embedded Toolchain: 10.3-2021.10 (GNU ARM Embedded 10.3.1.20210824)
QE	Renesas QE for BLE[RA,RE,RX] V1.4.0

Note: Please download and install tools from the following URL in advance.

- Renesas QE download site:
<https://www.renesas.com/software-tool/qe-tools-particular-applications>
- FSP with e² studio installer download site:
<https://github.com/renesas/fsp/releases>
- IAR EW for ARM download site:
<https://www.iar.com/products/architectures/arm/iar-embedded-workbench-for-arm>

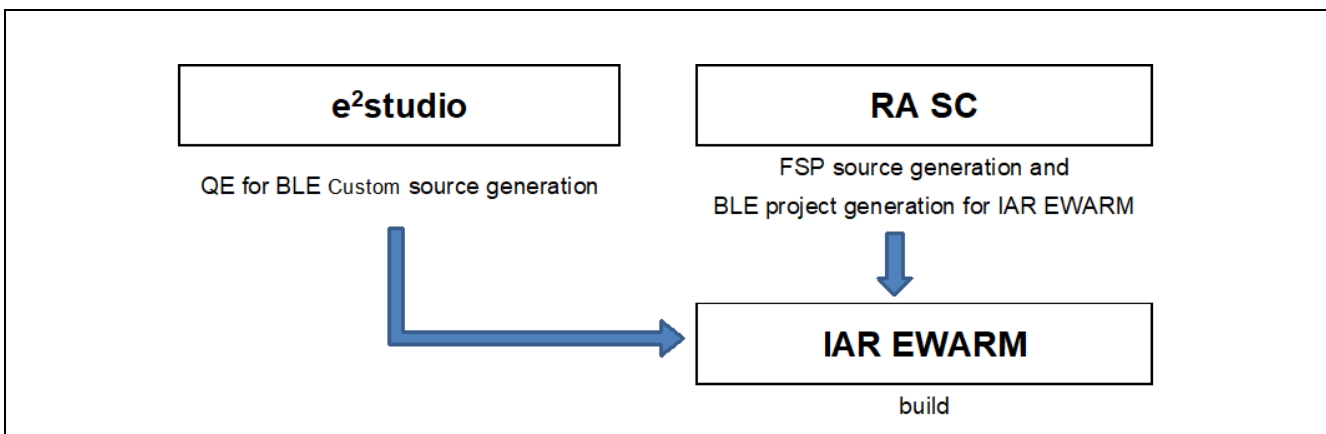


Figure 1. Configuration Diagram when using QE for BLE[RA,RE,RX] with IAR EWARM

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1. Creating a Project in e² studio

A project generation wizard is available in e² studio to generate a RA project with a project name and the associated device and board, including board-level drivers.

Start the e² studio application and choose a workspace folder in the Workspace Launcher. To create a new RA project, follow these steps.

1. Select **File > New > C/C++ Project**
2. Select **Renesas RA: Renesas RA C/C++ Project** template. Click **Next** to continue.

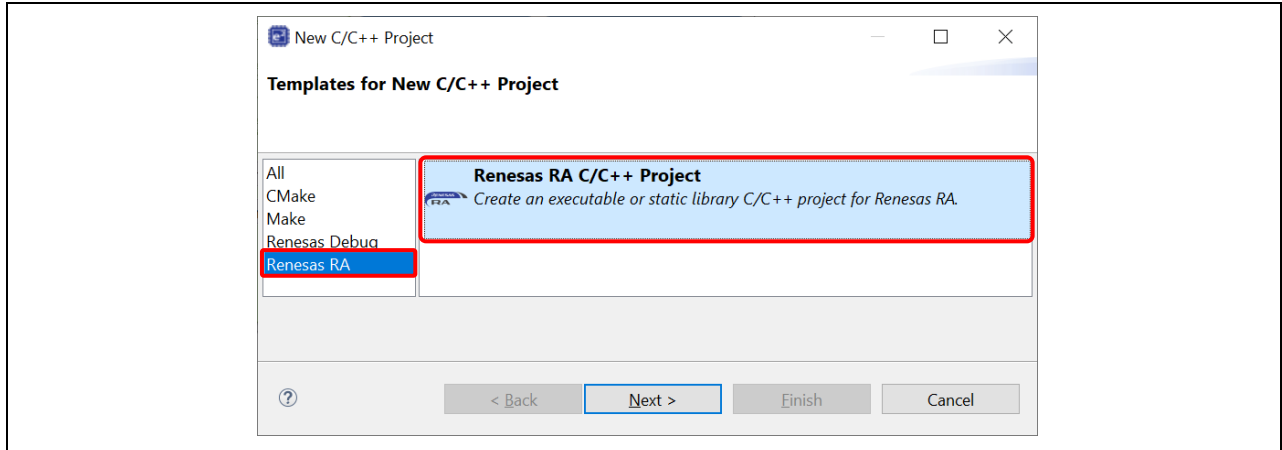


Figure 2. Templates Selection

3. In the next dialog box, enter a project name and click **Next**.

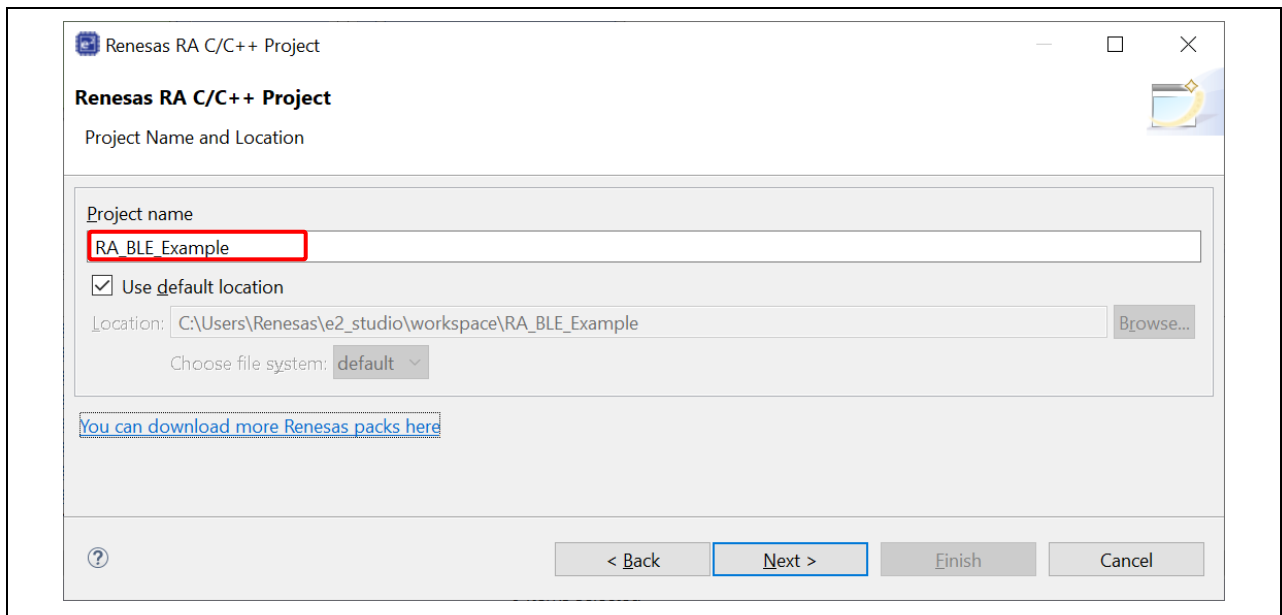


Figure 3. Project Name and Location

4. In the device selection dialog, enter device and tool information:

- Board: **EK-RA4W1**
- Device: Auto selected
- Language: **C**
- Toolchain version: Latest GNU Arm Embedded Toolchain approved for use with Renesas RA (for example, **GNU ARM Embedded 10.3.1.20210824**)
- Debugger: **J-link ARM**

Click **Next** to continue.

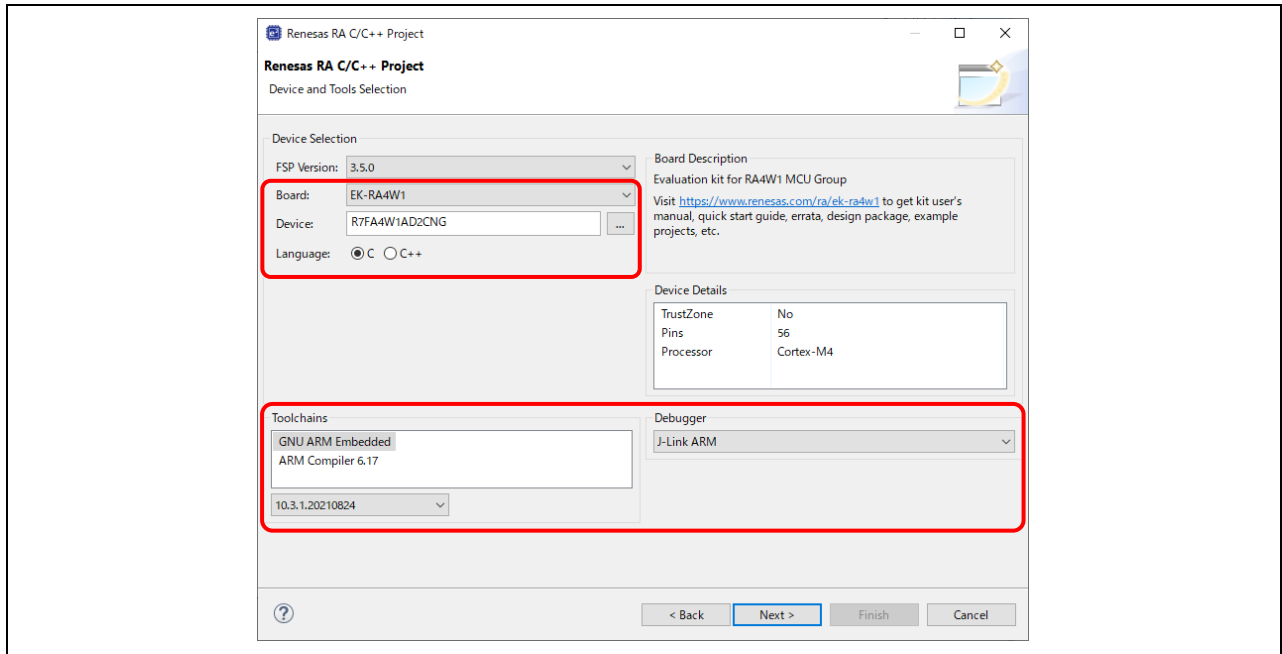


Figure 4. Create New Project For EK-RA4W1

5. Build Artifact Selection: **Executable**

RTOS Selection: **No RTOS**

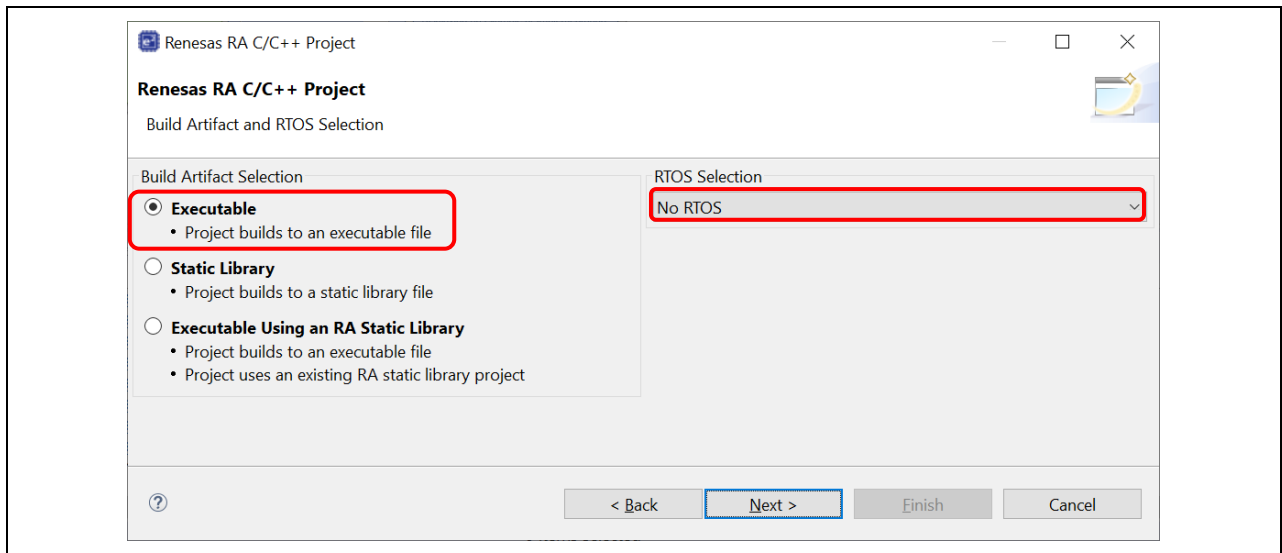


Figure 5. Build Artifact and RTOS Selection

6. In the project template dialog, select **Bare Metal - Minimal** and click **Finish**.

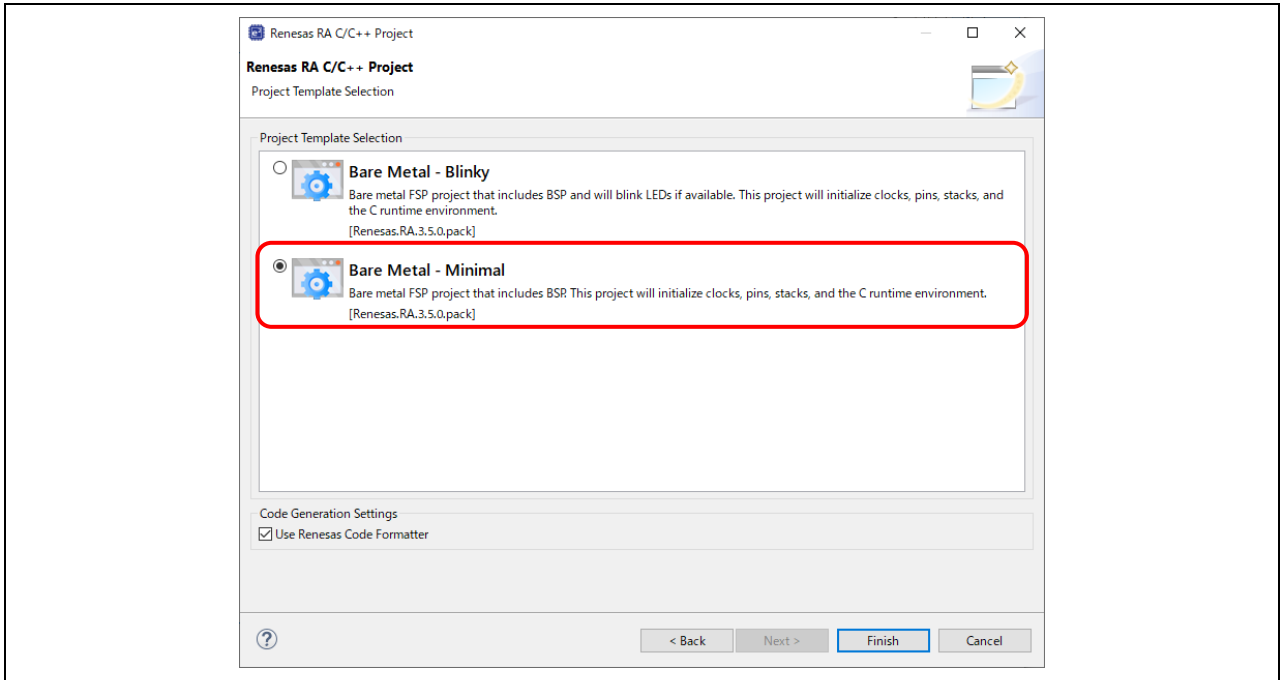


Figure 6. Project Template Selection

7. e² studio creates a project with the **FSP Configuration** perspective open and ready for project configuration.

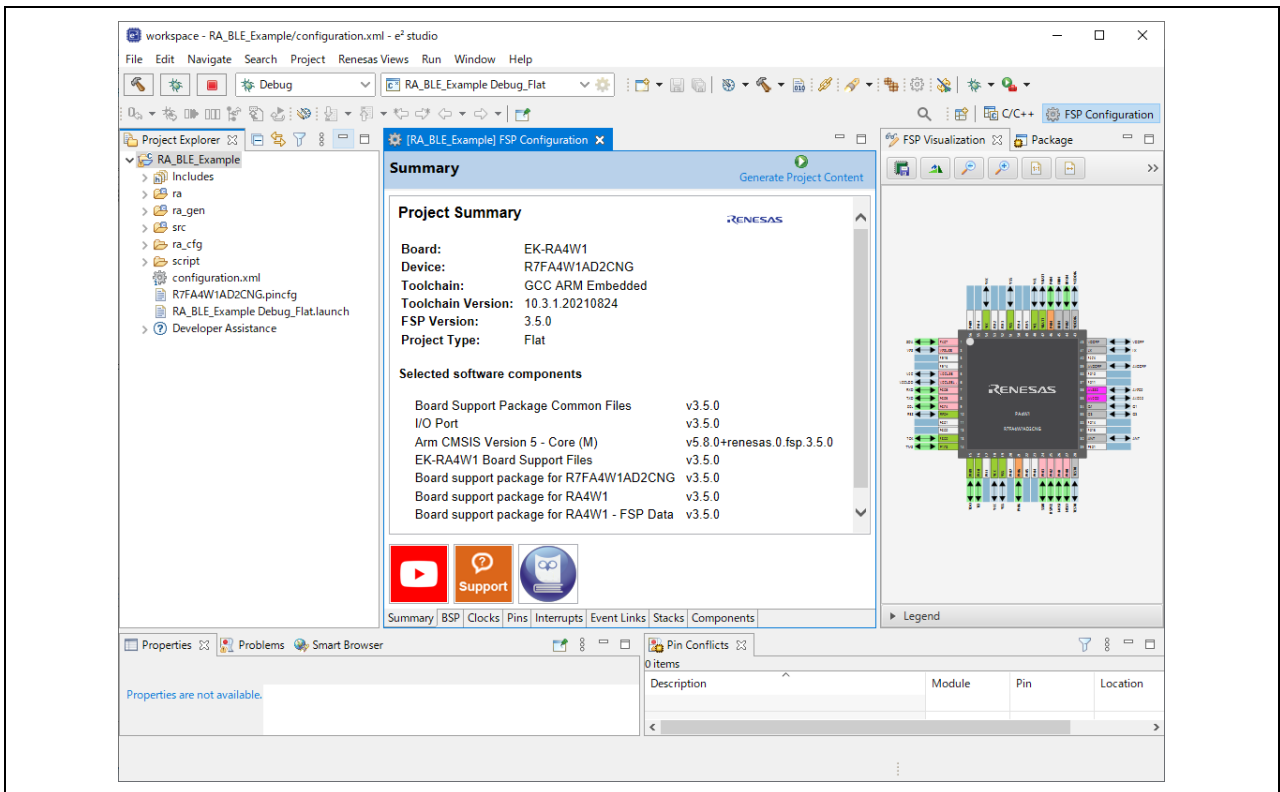


Figure 7. New Project is Opened with FSP Configuration Perspective

2. Creating BLE Custom Profile in e² studio

1. If **QE for BLE[RA,RE,RX]** has not been installed, select **Renesas Views > Renesas Software Installer** from the menu of e² studio to install it.
2. In the **Renesas Software Installer** dialog box, select **Renesas QE**, then click **Next**.
3. Select **QE for BLE[RA,RE,RX]** and click **Finish** to install it.

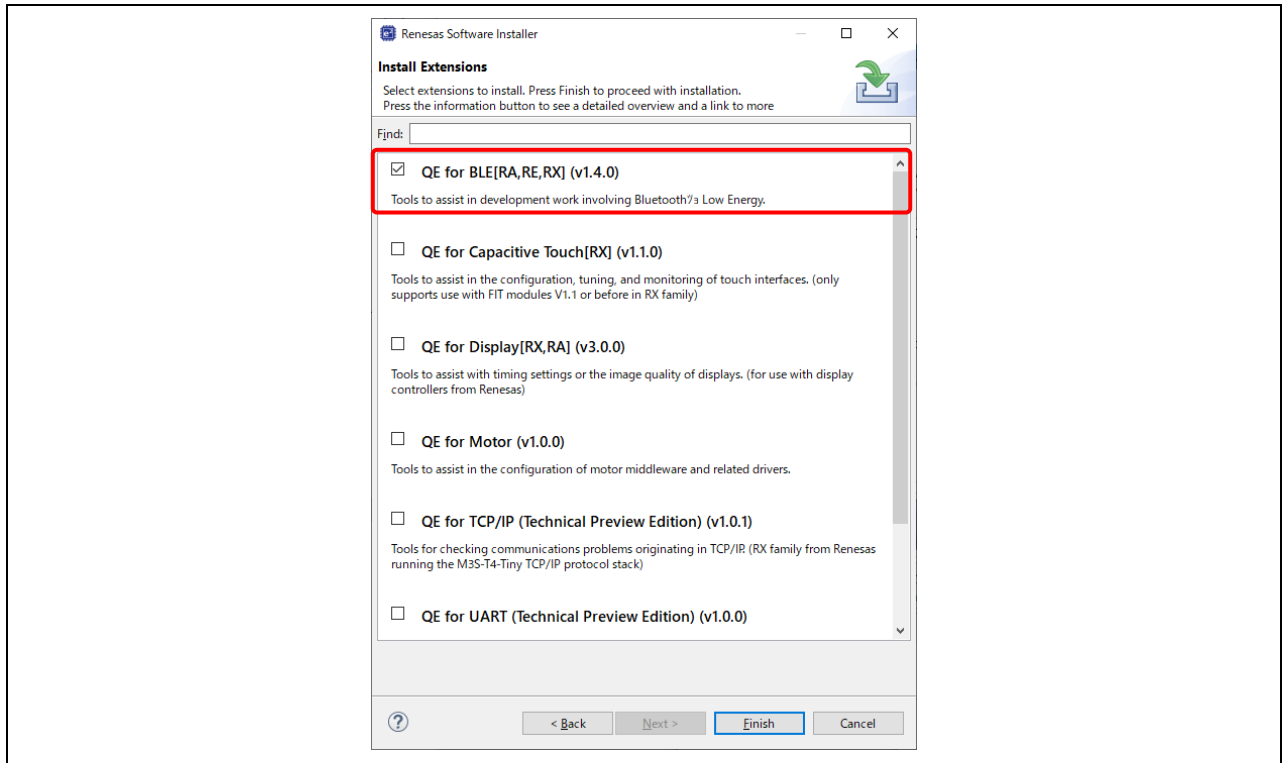


Figure 8. Install QE for BLE[RA,RE,RX]

4. From the menu of e² studio, select **Renesas Views > Renesas QE > R_BLE Custom Profile RA,RE,RX (QE)** to open the main perspective for configuring BLE custom profile to the project.

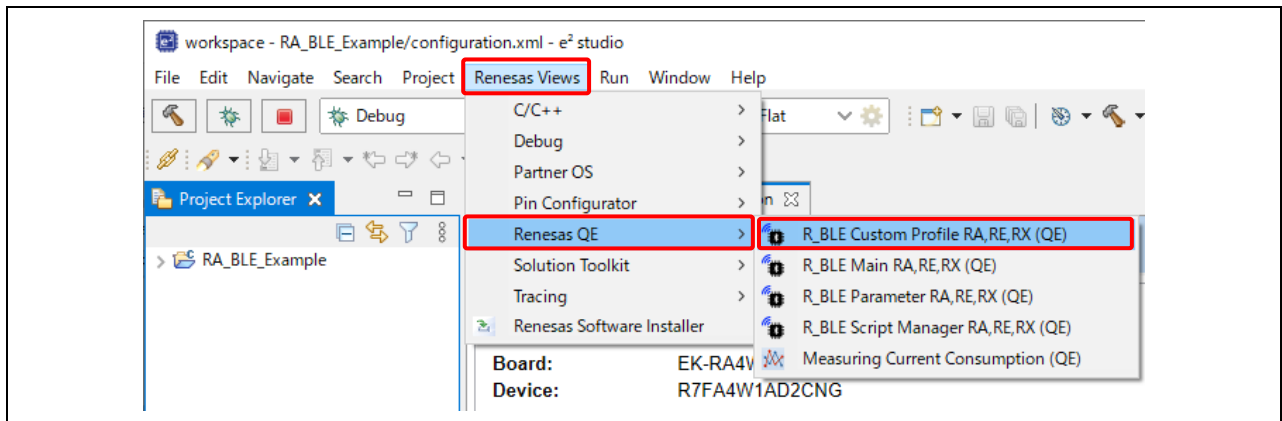


Figure 9. Open R_BLE Custom Profile RA,RE,RX (QE)

- 5. In the **R_BLE Custom Profile RA,RE,RX (QE)** pane, select the project to configure the BLE custom profile by using the pull-down tab and selecting the **RA_BLE_Example** project as shown below.

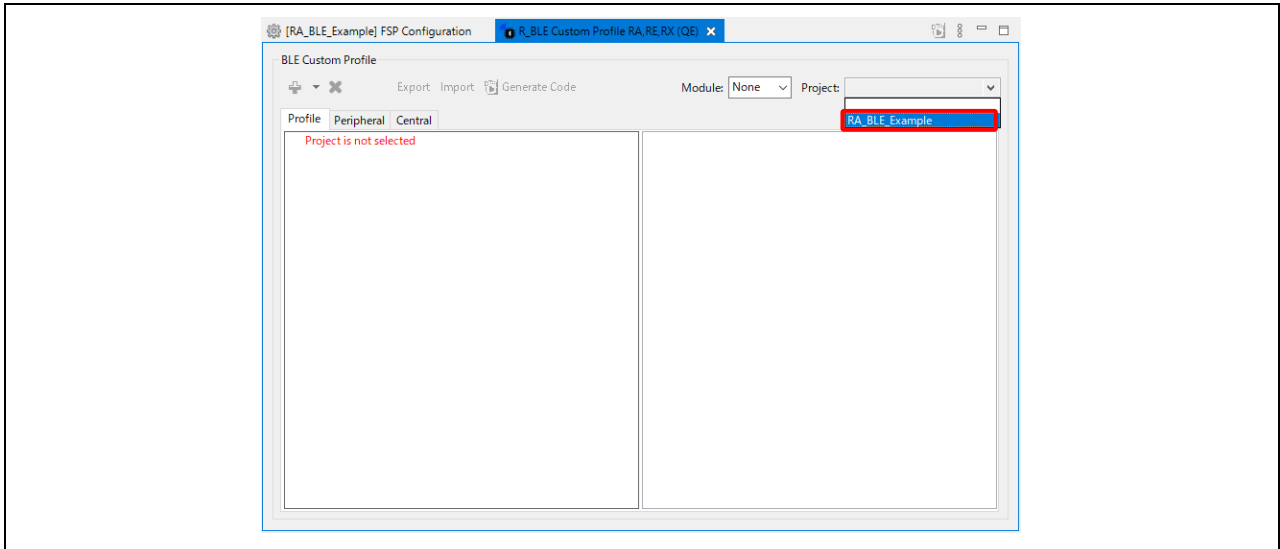


Figure 10. Select Project

- 6. Select **Profile**, then click the **Add** button and select **Add Service** to add new BLE service.

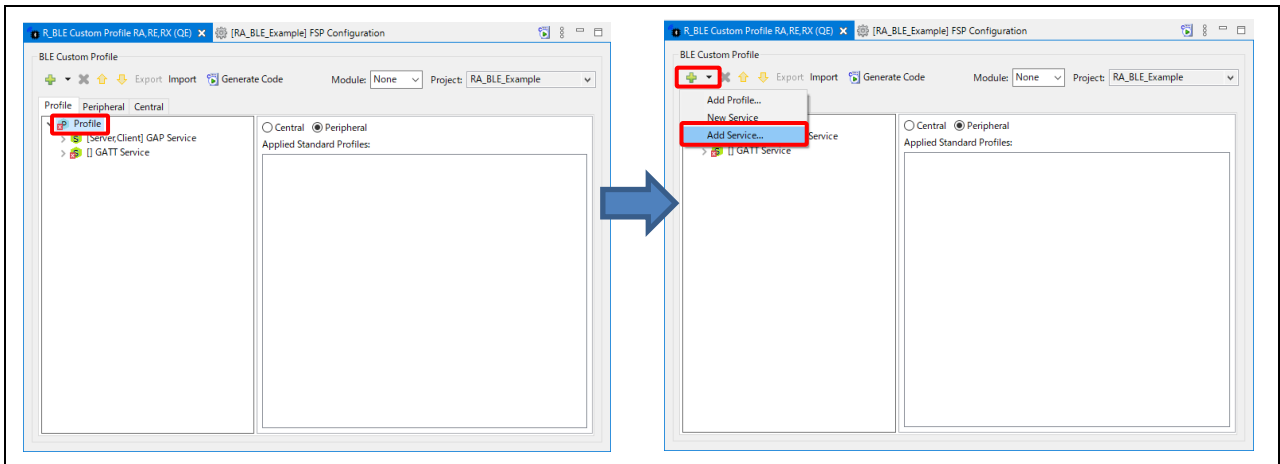


Figure 11. Add New Service

- 7. Type **LED** in the filter box and select **LED Switch Service**. Click **OK**.

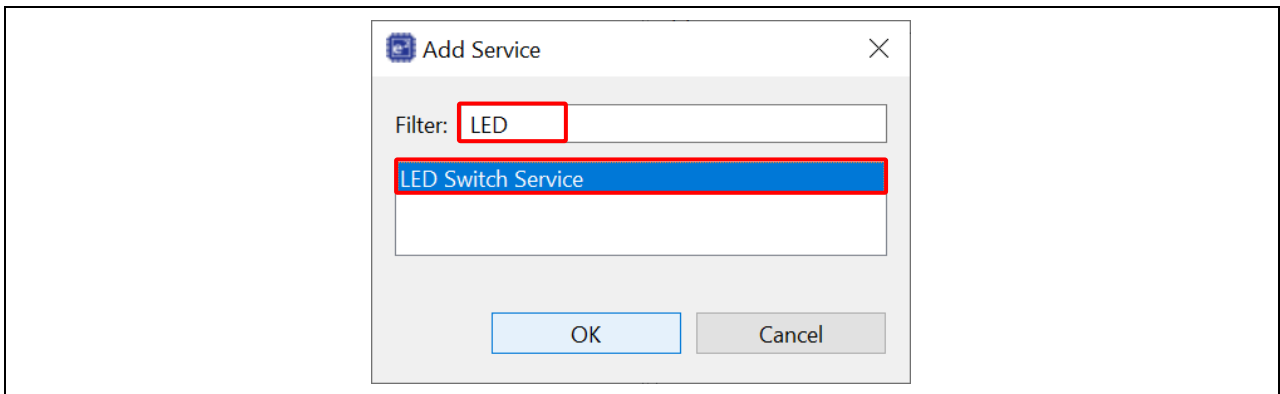


Figure 12. Add LED Switch Service

8. Click **Generate Code** button to generate code.

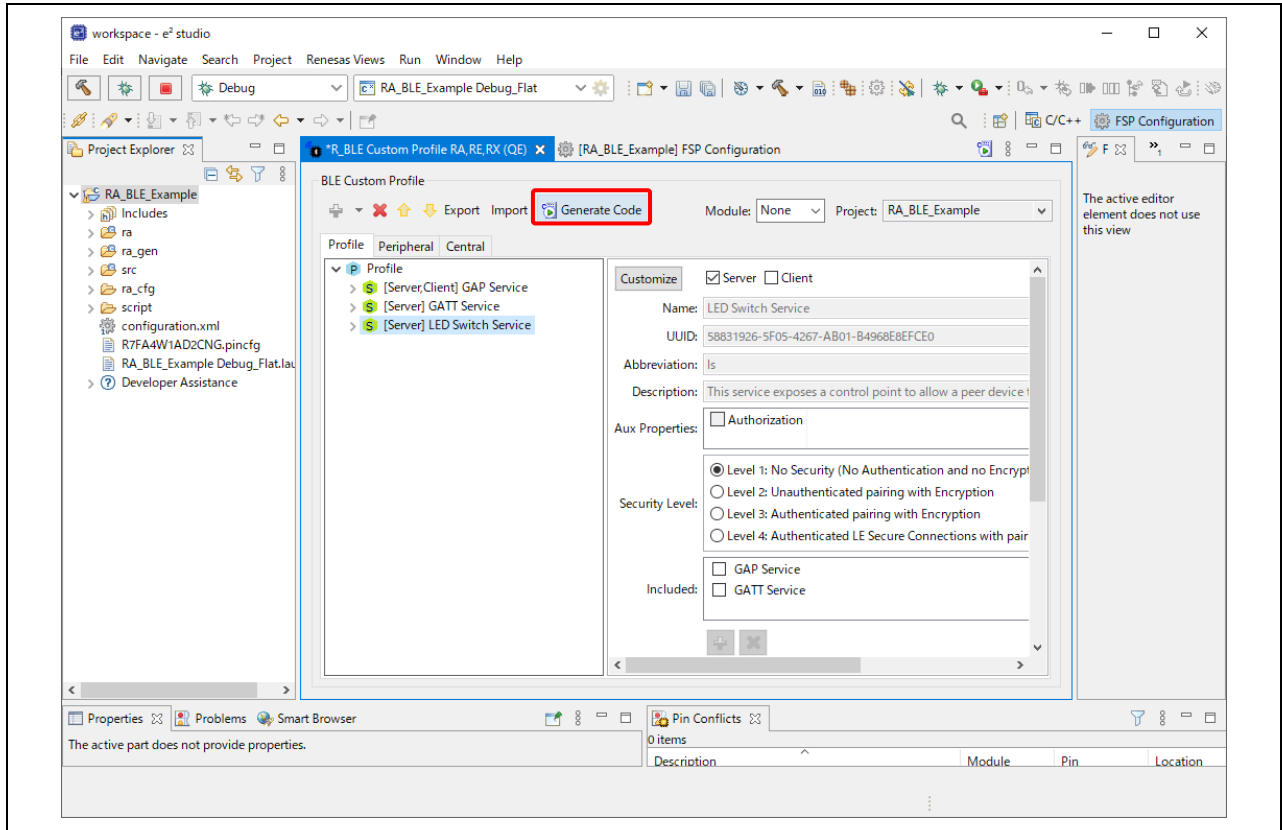


Figure 13. Generate Code

9. In the **Project Explorer** window, you will see that new folders and source files have been added to **Project > qe_gen > ble** folder. These files contain the necessary information to enable BLE using the drivers of FSP.

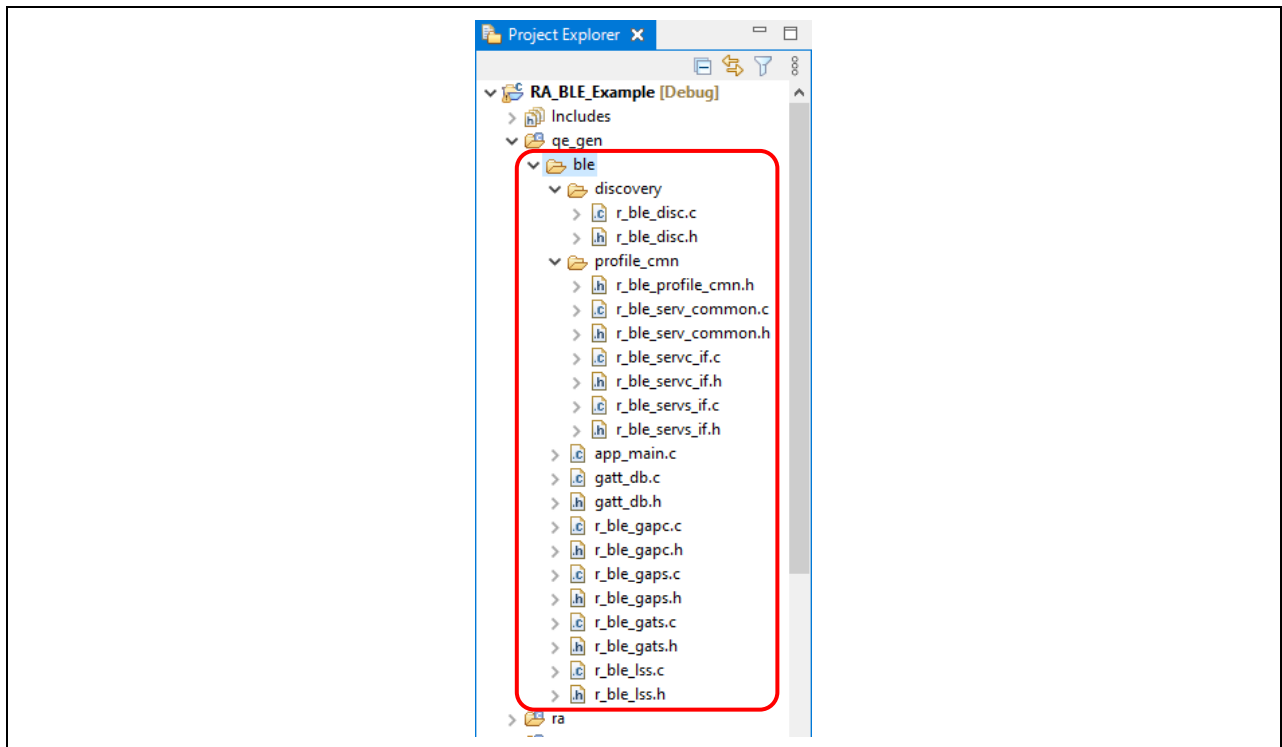


Figure 14. QE for BLE sources

3. Creating a Project in IAR EWARM

1. Install the IAR Embedded Workbench for ARM version 9.20.2 from <https://www.iar.com/products/architectures/arm/iar-embedded-workbench-for-arm>.
2. Install the Smart Configurator (RA SC) from <https://www.renesas.com/smart-configurator>.
Note: Please check the version of the Smart Configurator installer. If the FSP is not v3.5.0, download and install the latest version from <https://github.com/renesas/fsp/releases>.
3. To create a third-party IDE project with the Smart Configurator, run the “rasc.exe” application. In the **New Renesas RA FSP Project** wizard, enter the **Project Name** and **Location**.

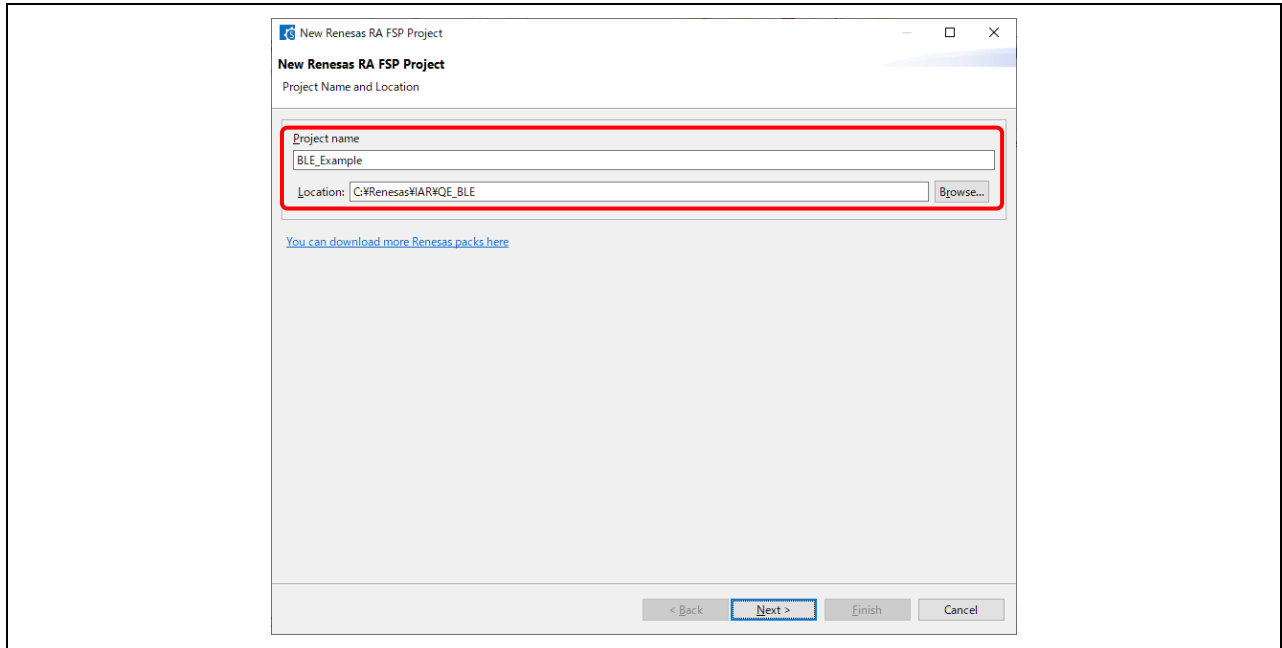


Figure 15. Project Name and Location

4. In the device selection dialog, enter device and IDE information:
 - Board: **EK-RA4W1**
 - Device: Auto selected
 - Language: **C**
 - IDE Project Type: **IAR EWARM Version 8**
 - Toolchains: IAR Toolchain for ARM
- Click **Next** to continue.

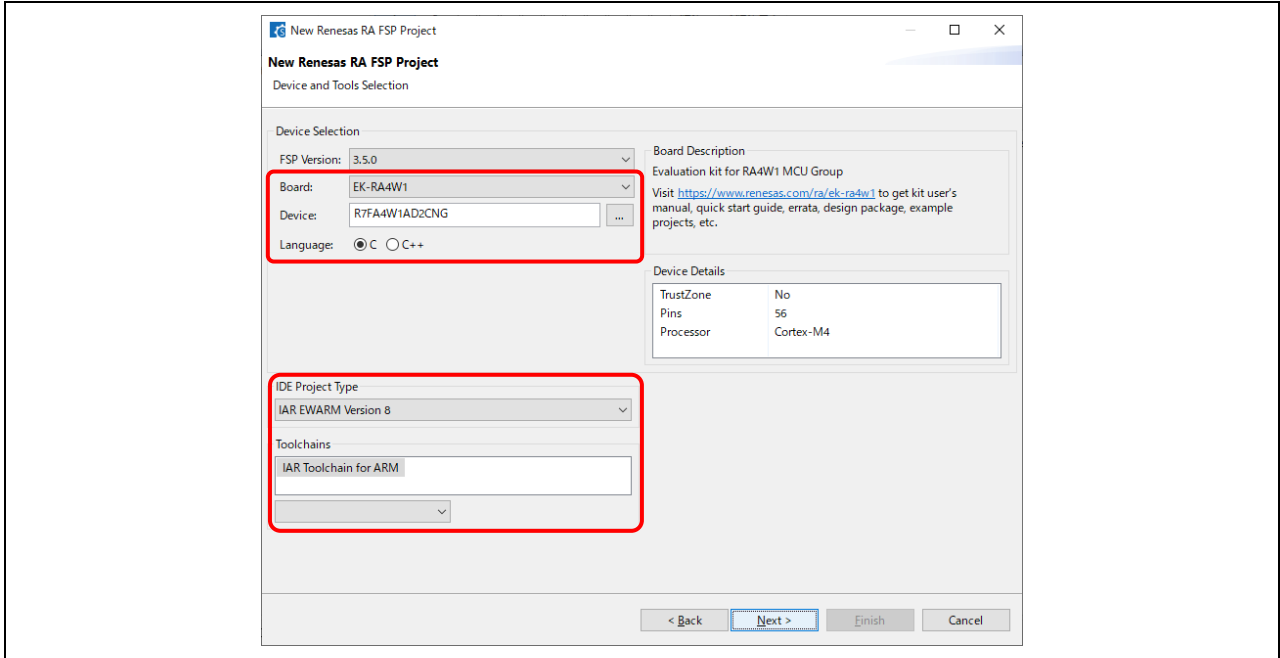


Figure 16. Board Selection for EK-RA4W1

5. RTOS Selection: **No RTOS**. Click **Next** to continue.

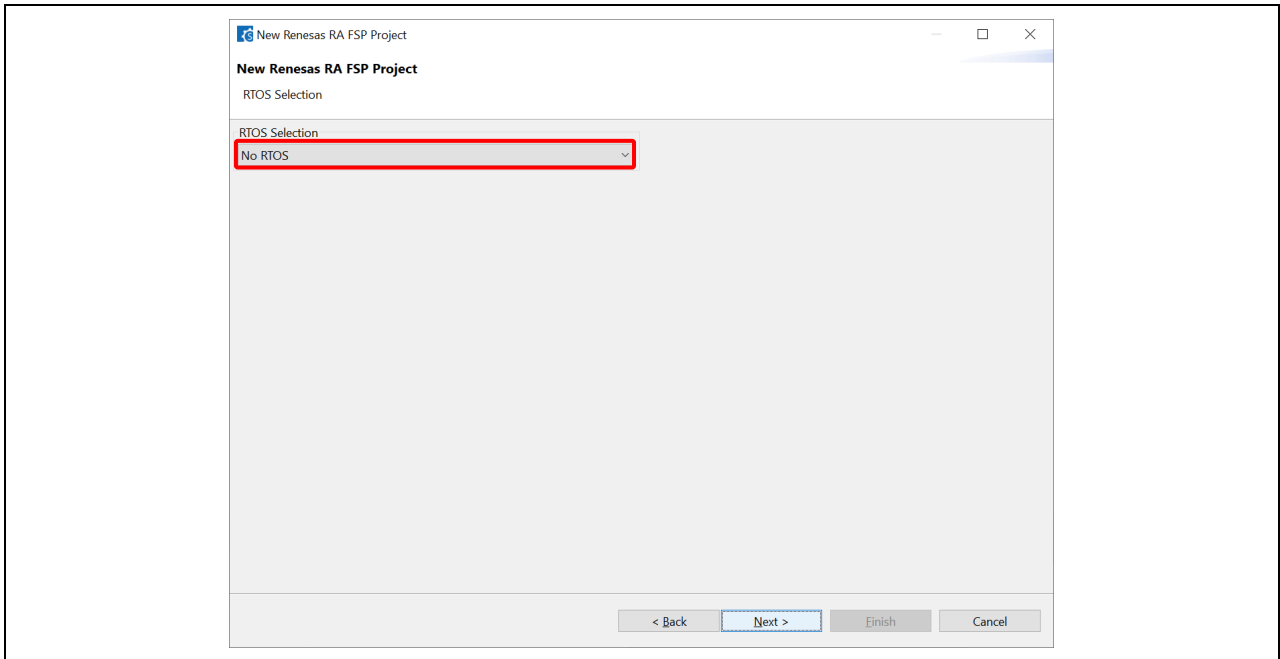


Figure 17. RTOS Selection

6. Project Template Selection: **Bare Metal – Minimum**. Click **Finish** to create project.

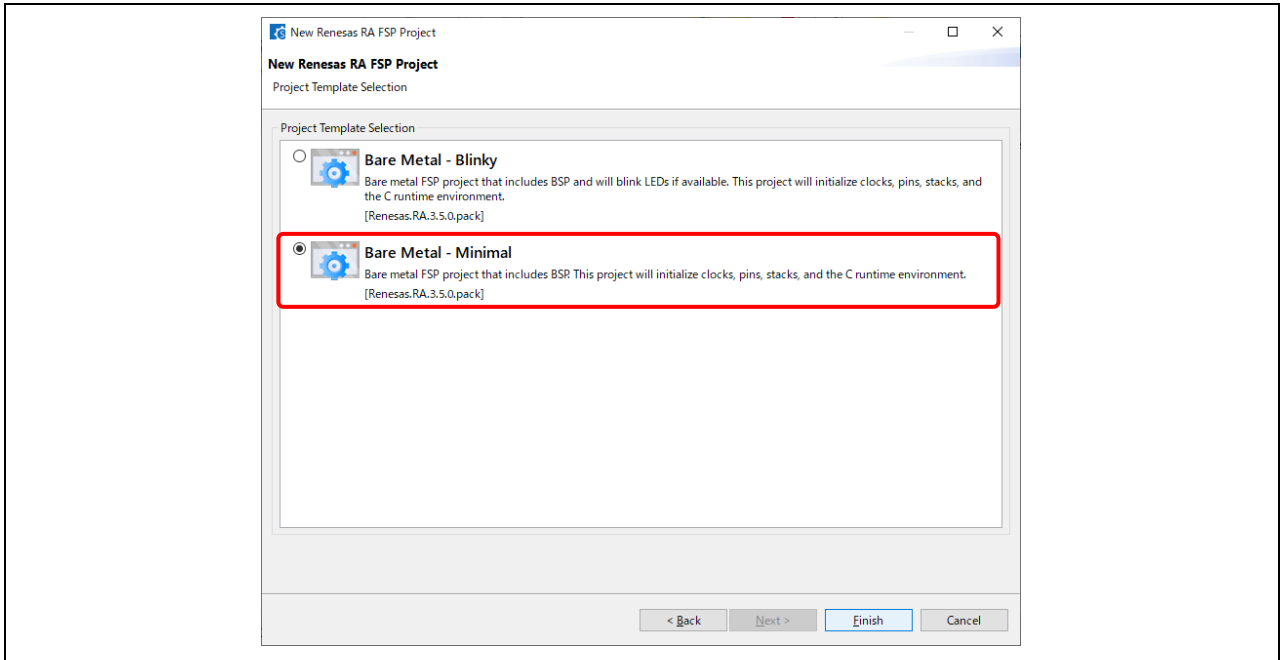


Figure 18. Template Selection

7. After creating the project, the Smart Configurator window will pop-up.

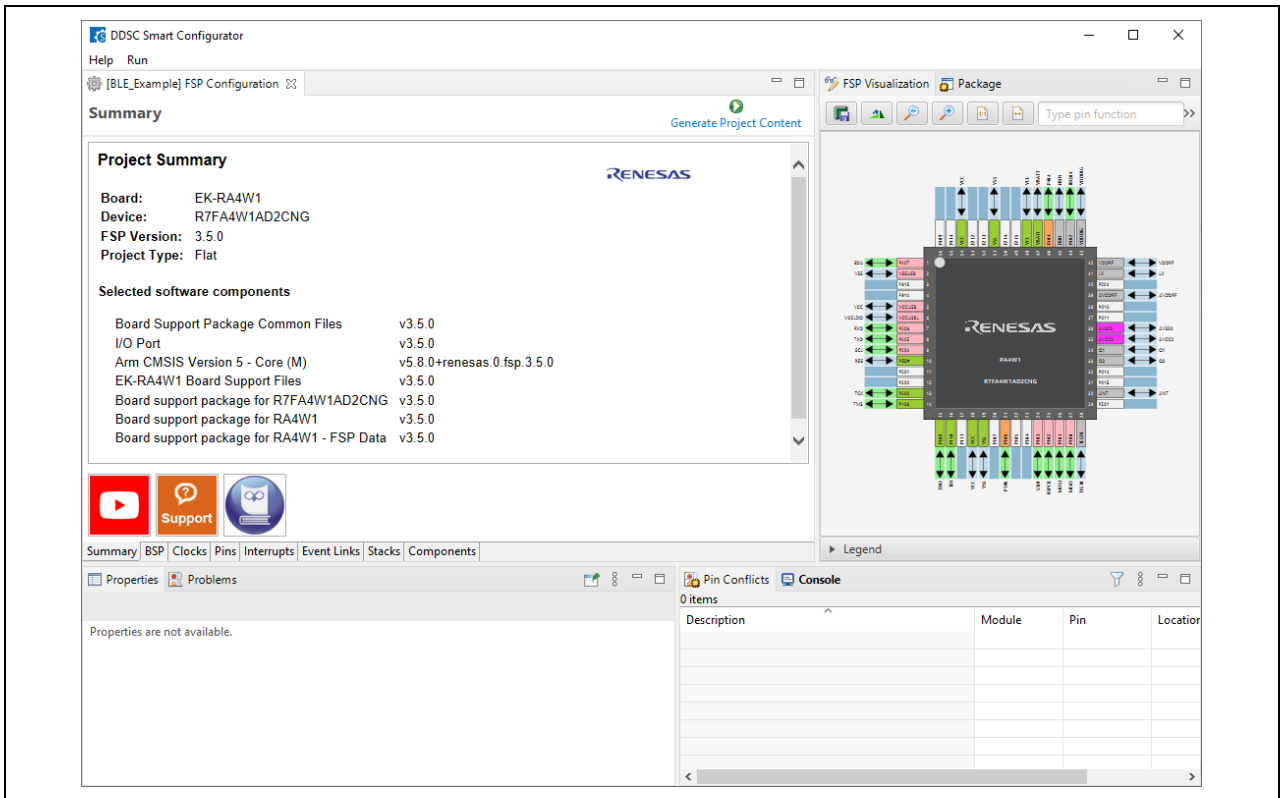


Figure 19. Smart Configurator Window

- In Windows Explorer, navigate to the folder you entered in 3.3. and see that the main workspace (IAR EWARM *.eww file) exists. Close the Smart Configurator window, then double-click on the main workspace to open the project.

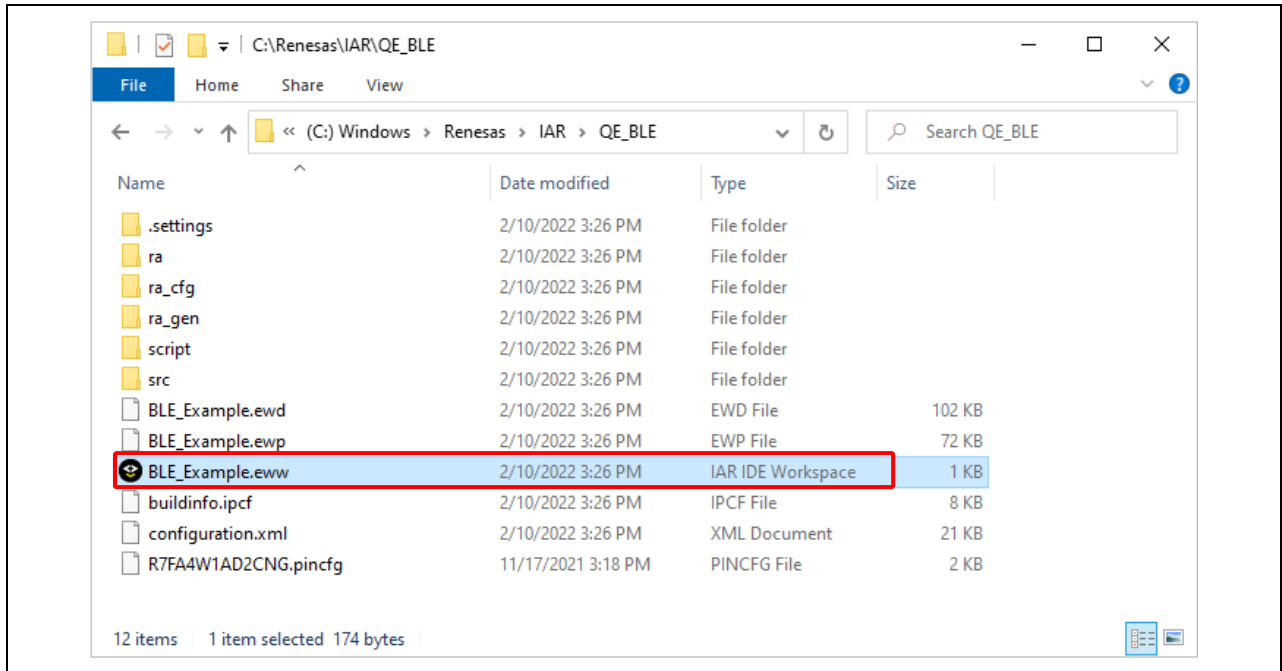


Figure 20. Project Location

- Project is opened by IAR EWARM. Right-click on the project and select **Rebuild All**. The project should be built without error.

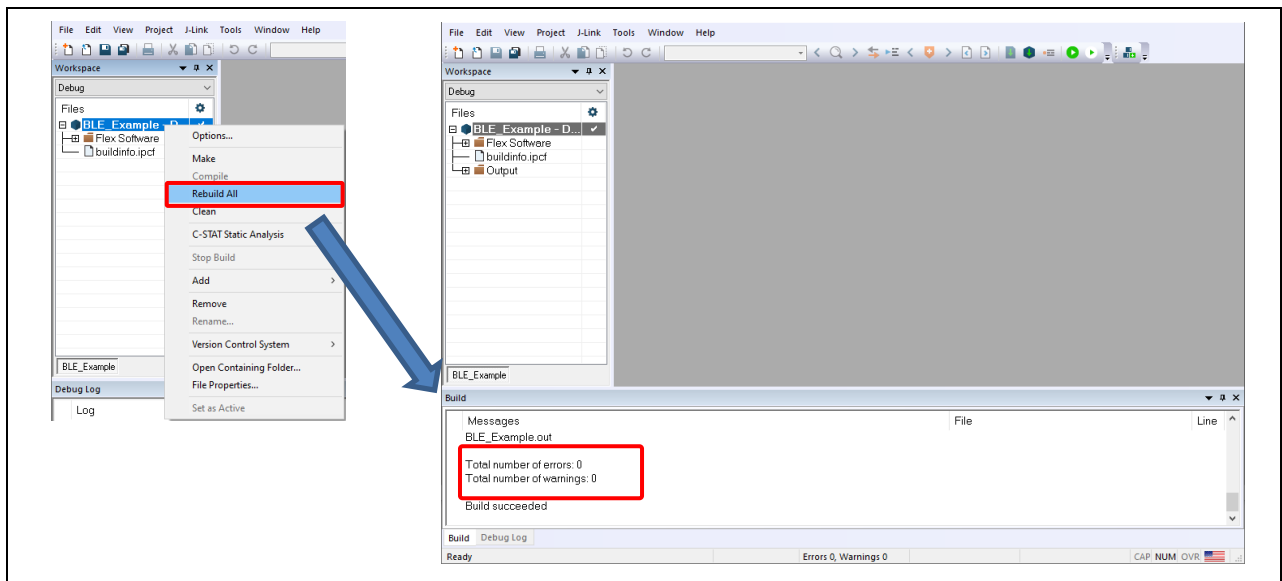


Figure 21. Project is Built Successfully

10. After a project created with the Smart Configurator has been opened in IAR EWARM, its FSP configuration can be changed by relaunching the Smart Configurator from the IDE. Follow the instructions below to reopen the Smart Configurator.
11. In the menu of IAR EWARM, select **Tools > Configure Tools...** Then, select **New** and fill in the fields as follows.

Menu Text: **RA Smart Configurator**
 Command: Select **Browse...** and navigate to **rasc.exe**
 Argument: **-compiler IAR configuration.xml**
 Initial Directory: **\$PROJ_DIR\$**

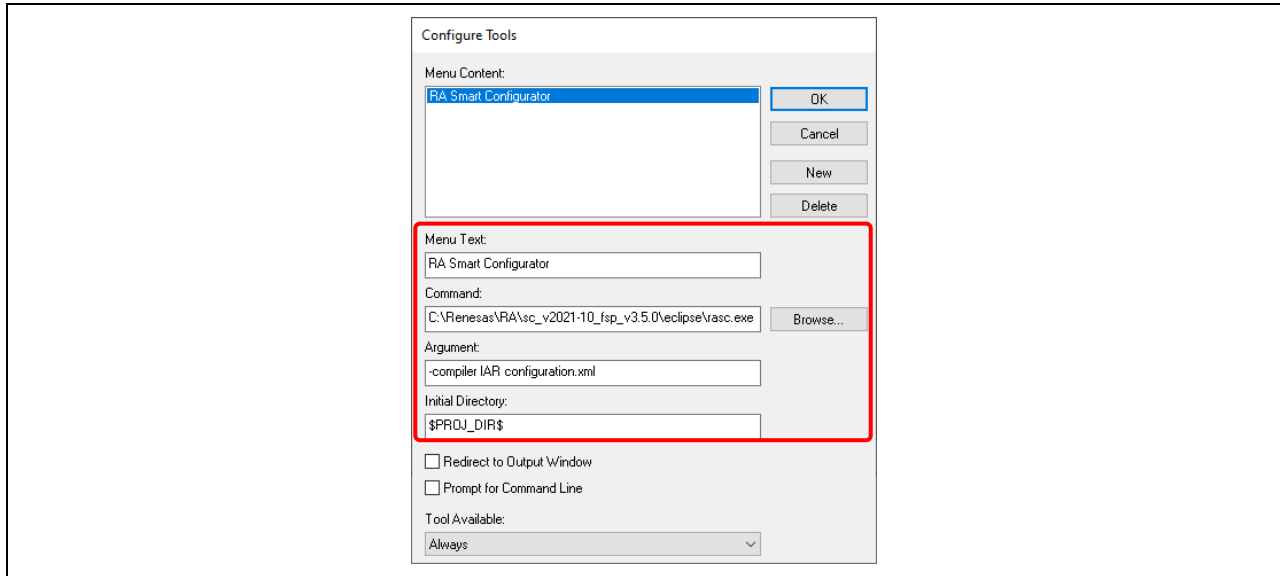


Figure 22. How To Use Smart Configurator in IAR EWARM

12. Now, a FSP configuration of a created project can be reopened by select **Tool > RA Smart Configurator** in IAR EWARM.

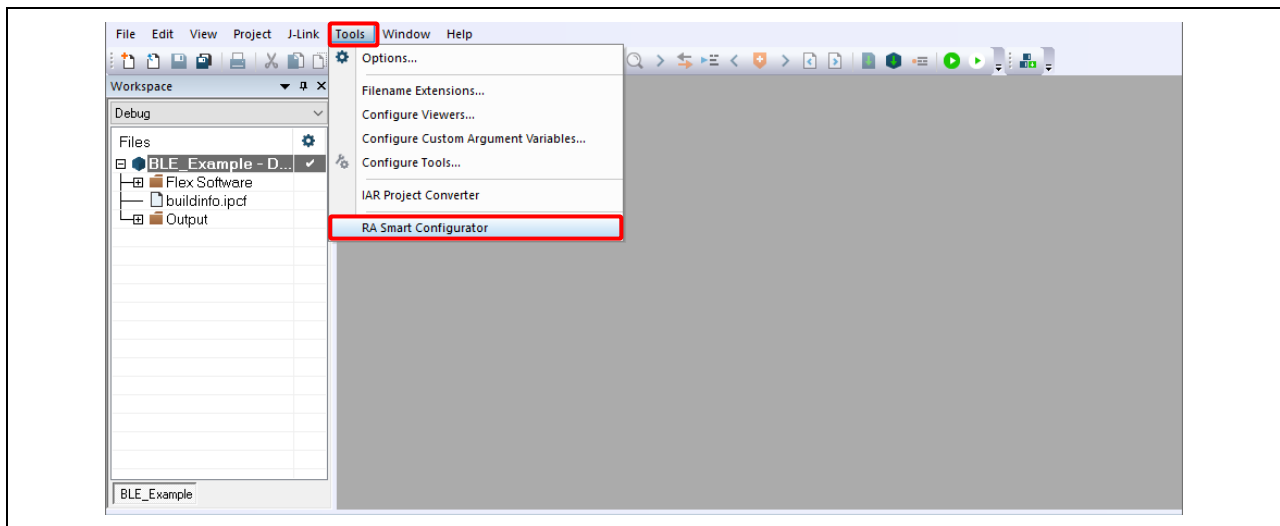


Figure 23. RA Smart Configurator Has Been Added

4. Adding BLE Driver in IAR EWARM

1. Open Smart Configurator, go to **Stacks** tab. Select **New Stack > Networking > BLE Abstraction (rm_ble_abs)**.

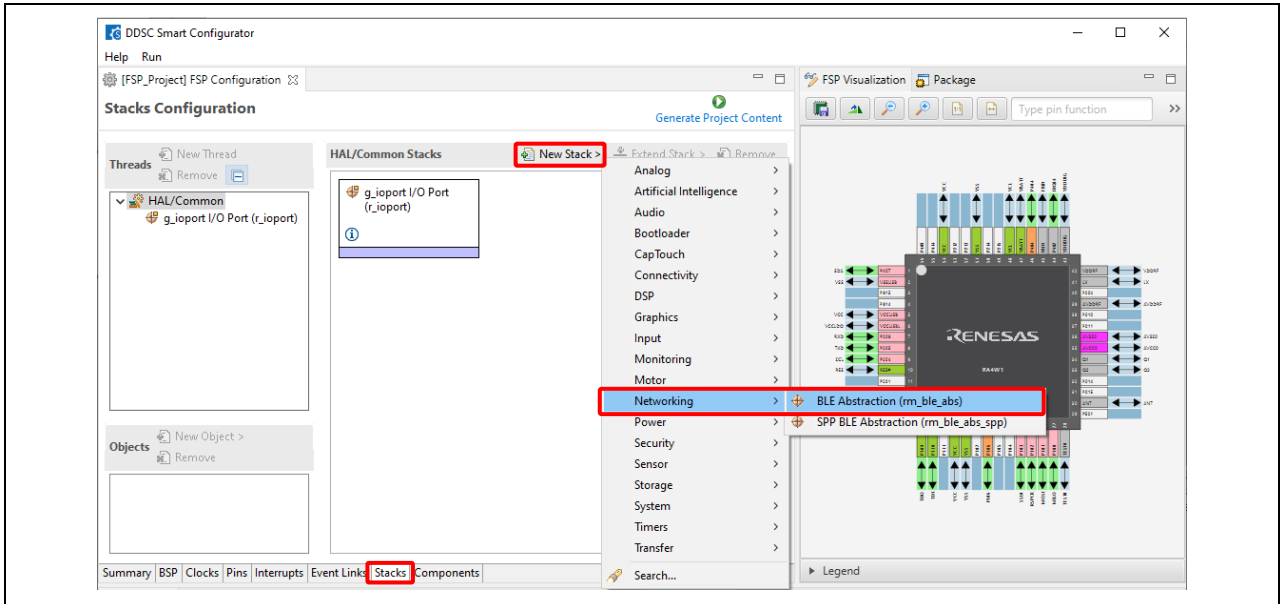


Figure 24. Add BLE Abstraction Driver

2. Click on **Add BLE Library for Network** and select **New > BLE Driver (r_ble_extended)**.

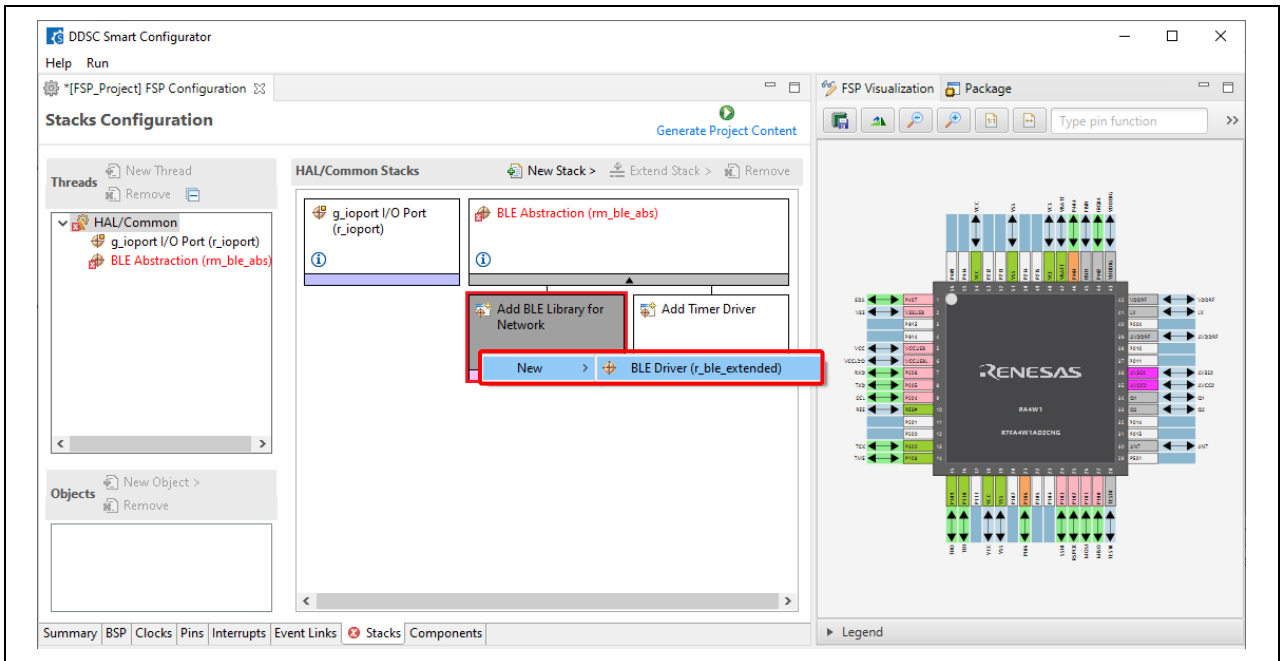


Figure 25. Add Network Driver

3. Click on **Add Timer Driver** and select **New > Timer, Low-Power (r_agt)**.

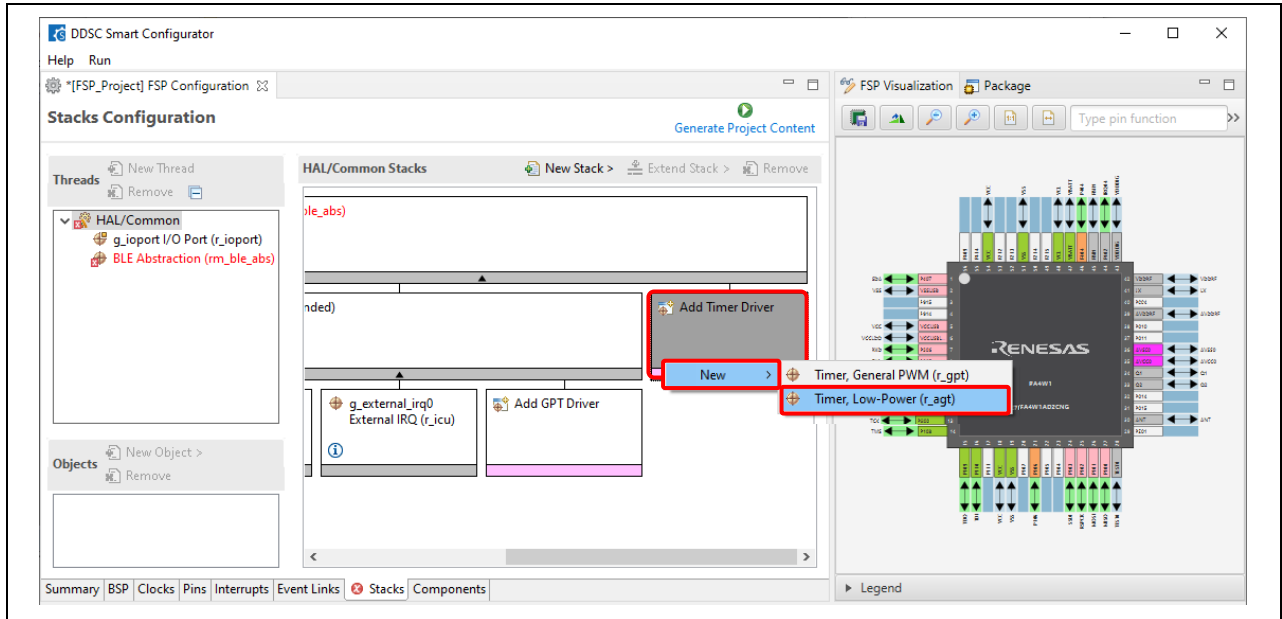


Figure 26. Add Timer Driver

4. Select the **r_agt** driver, in the **Property** window, enable the **Underflow Interrupt Priority** by changing it to **priority 4**.

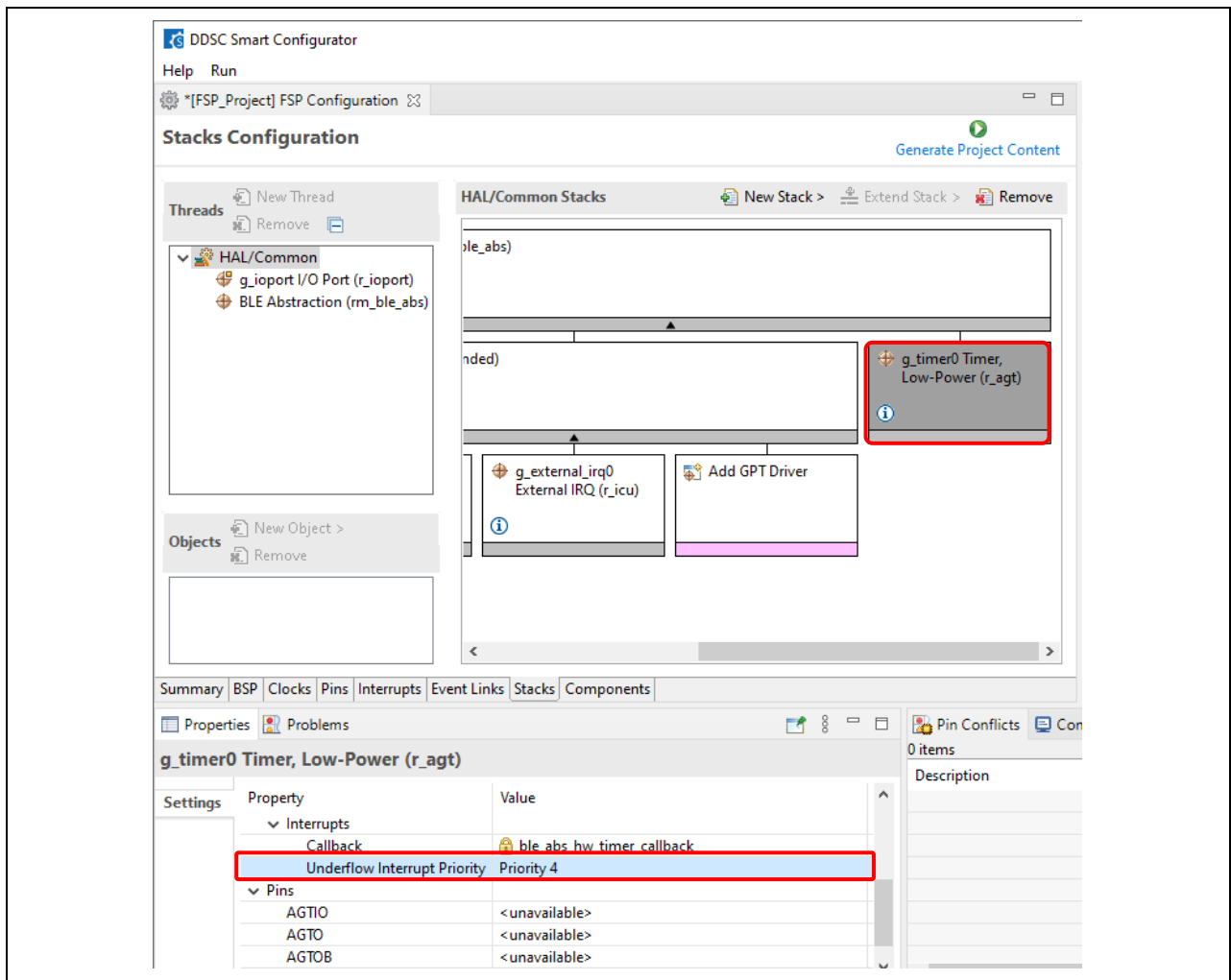


Figure 27. Enable AGT interrupt

5. Click on **Add GPT Driver** and select **New > Timer, General PWM (r_gpt)**.

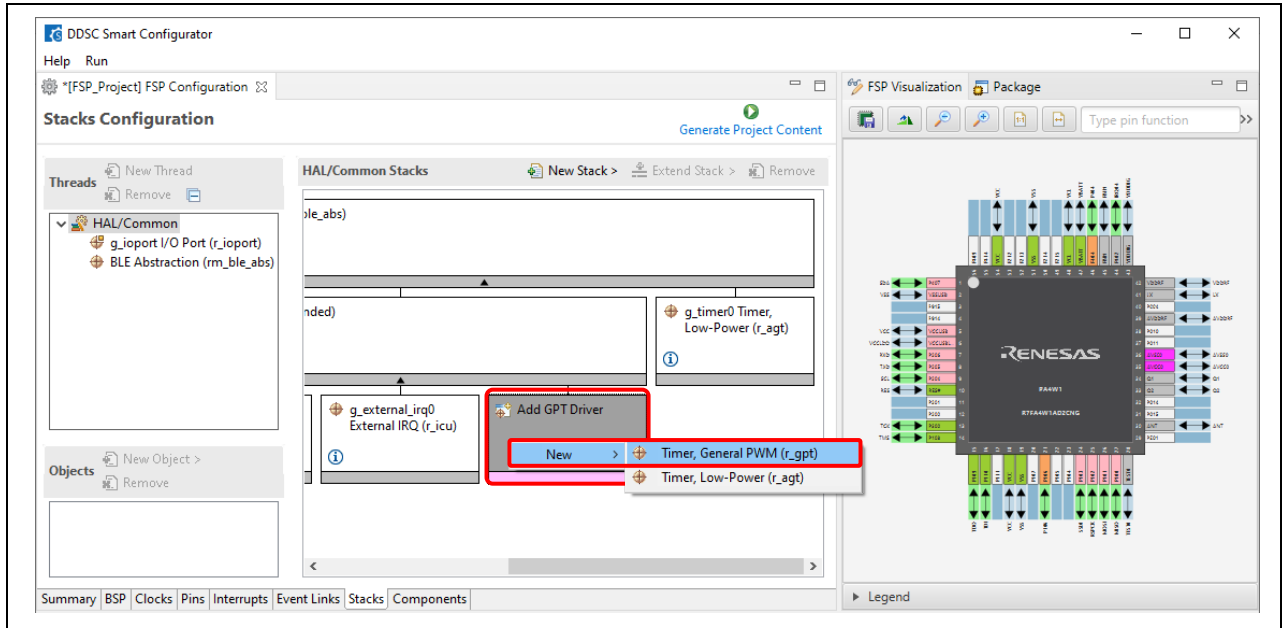


Figure 28. Add GPT Driver

6. Select the **r_gpt** driver, in the **Property** window, enable the **Overflow/Crest Interrupt Priority** by changing it to **priority 2**.

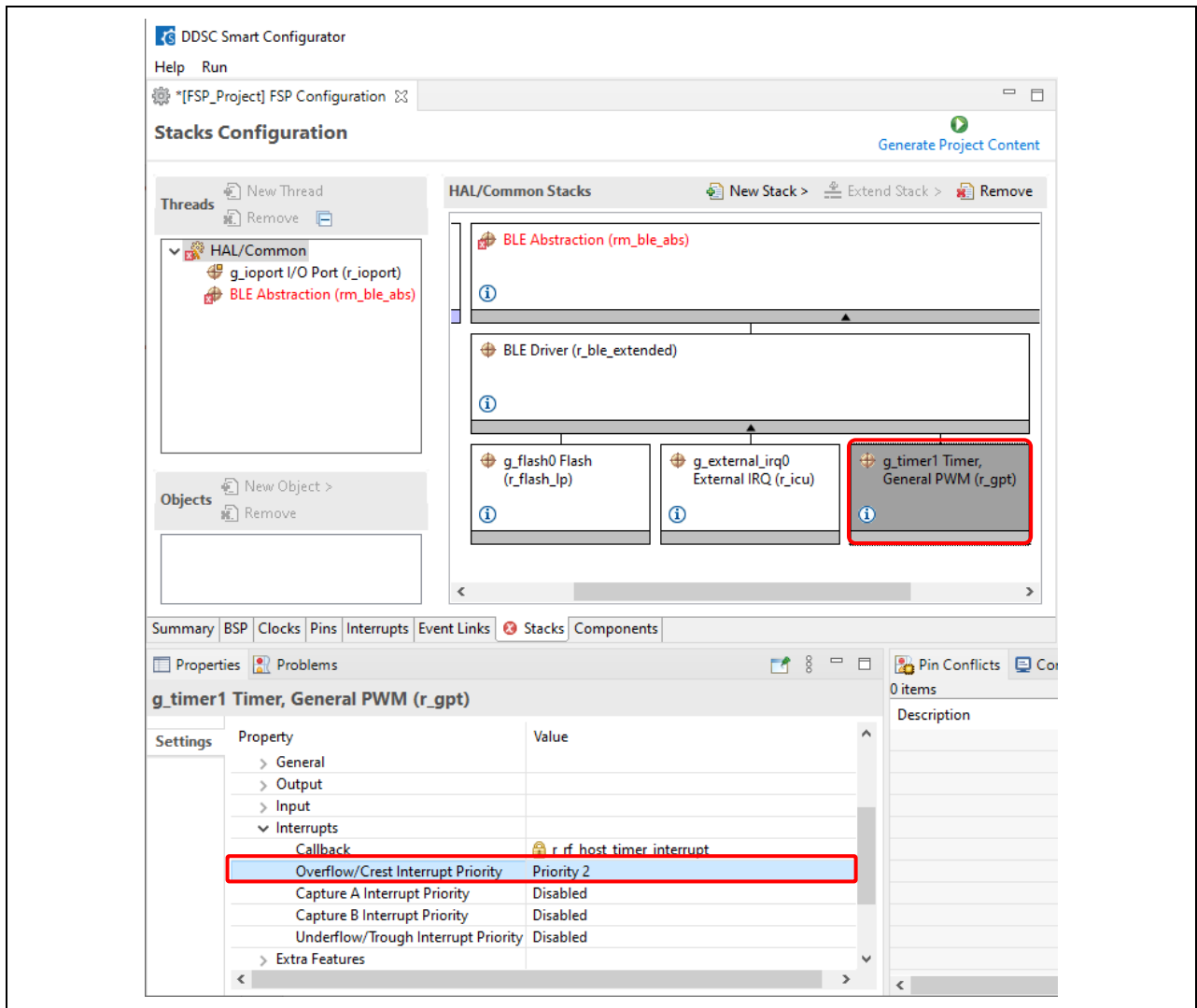


Figure 29. Enable GPT Interrupt

7. Click on **BSP** tab, in the **Property** window, change **Heap size** to **0x2000**.

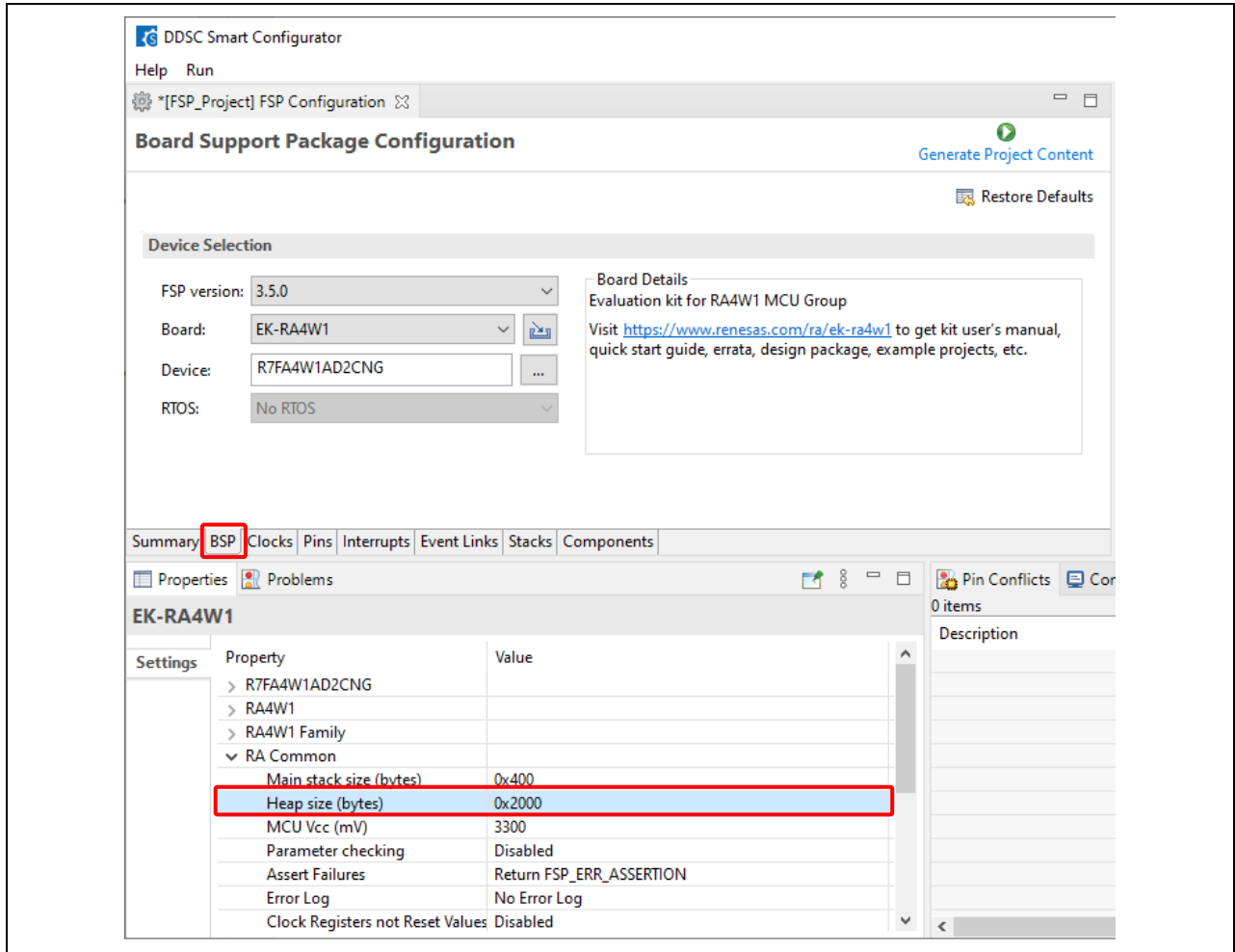


Figure 30. Change Heap Size

8. Click on the **Generate Project Content** button to generate source file.

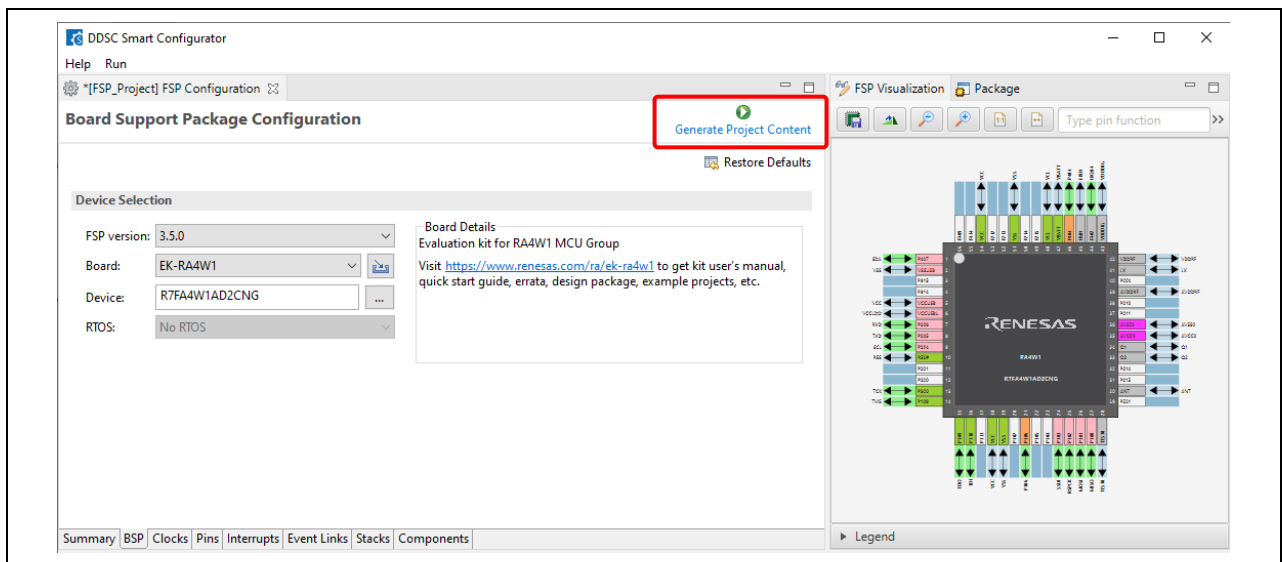


Figure 31. Generate Project Content

5. Copying QE files to IAR EWARM

1. In e² studio, right-click the **ble** folder, select **Copy** from the menu, and paste it into the IAR EWARM project folder.

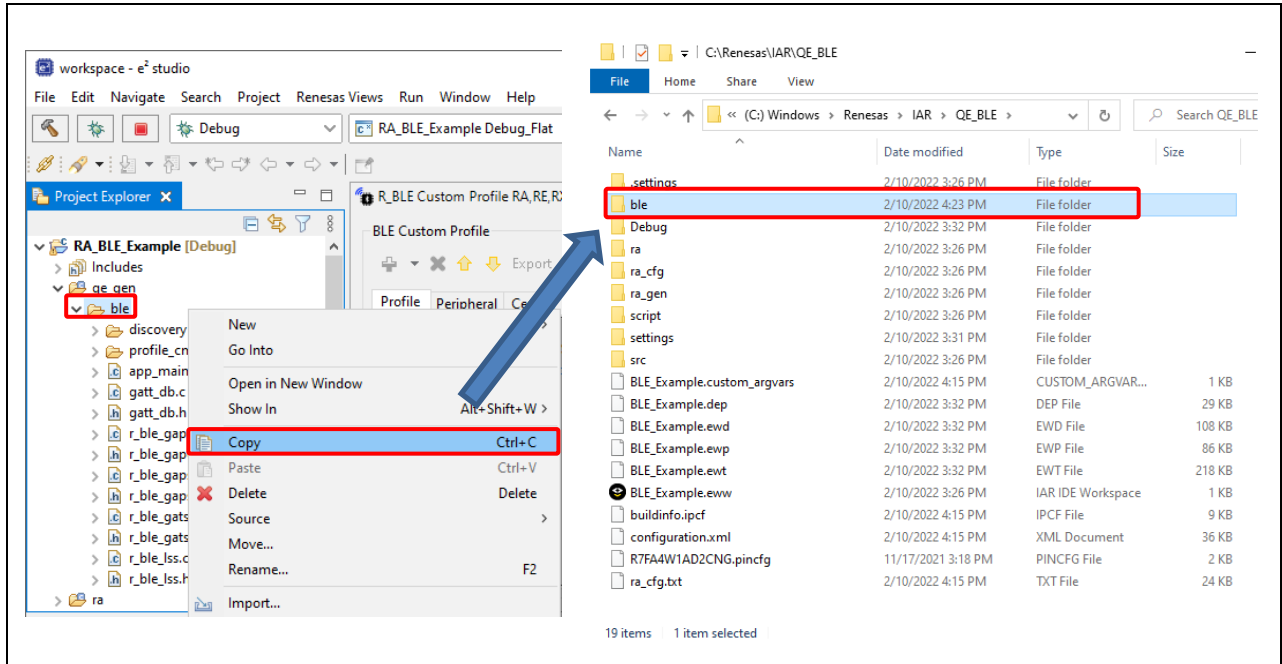


Figure 32. Copy ble Folder to IAR

2. In IAR EWARM, right-click on the project name and select **Add > Add Group...** Enter the group name “ble” and click **OK**.

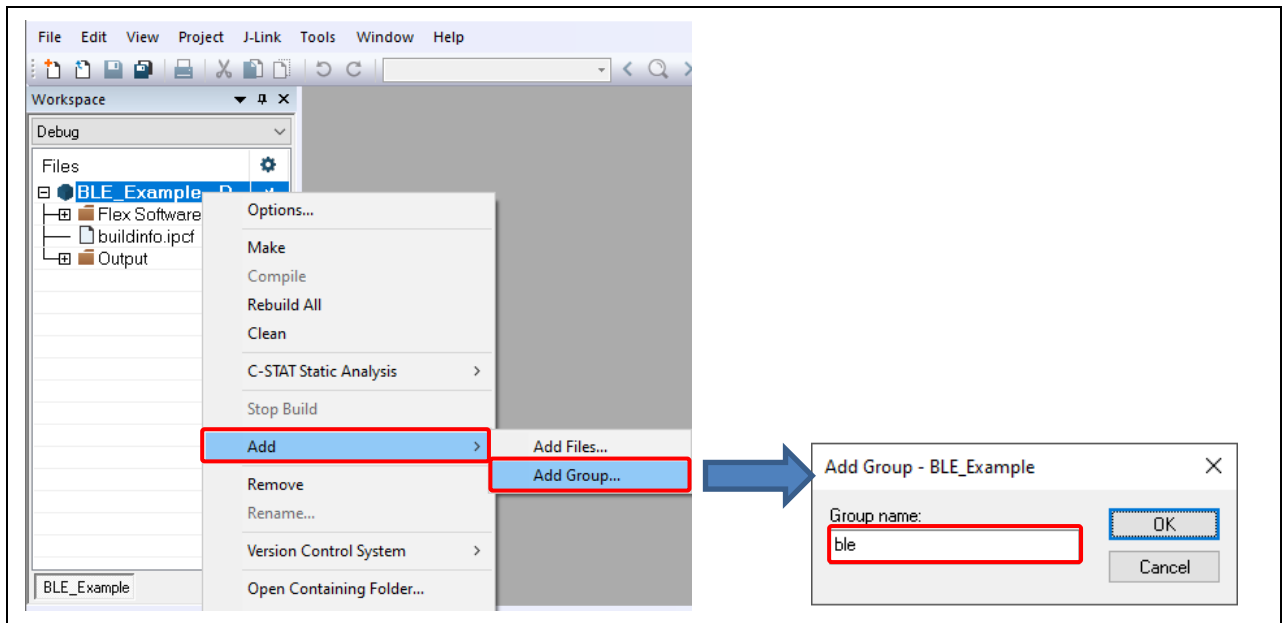


Figure 33. Create New Group

3. Continue to add two more groups: **discovery** and **profile_cmn** in **ble**.

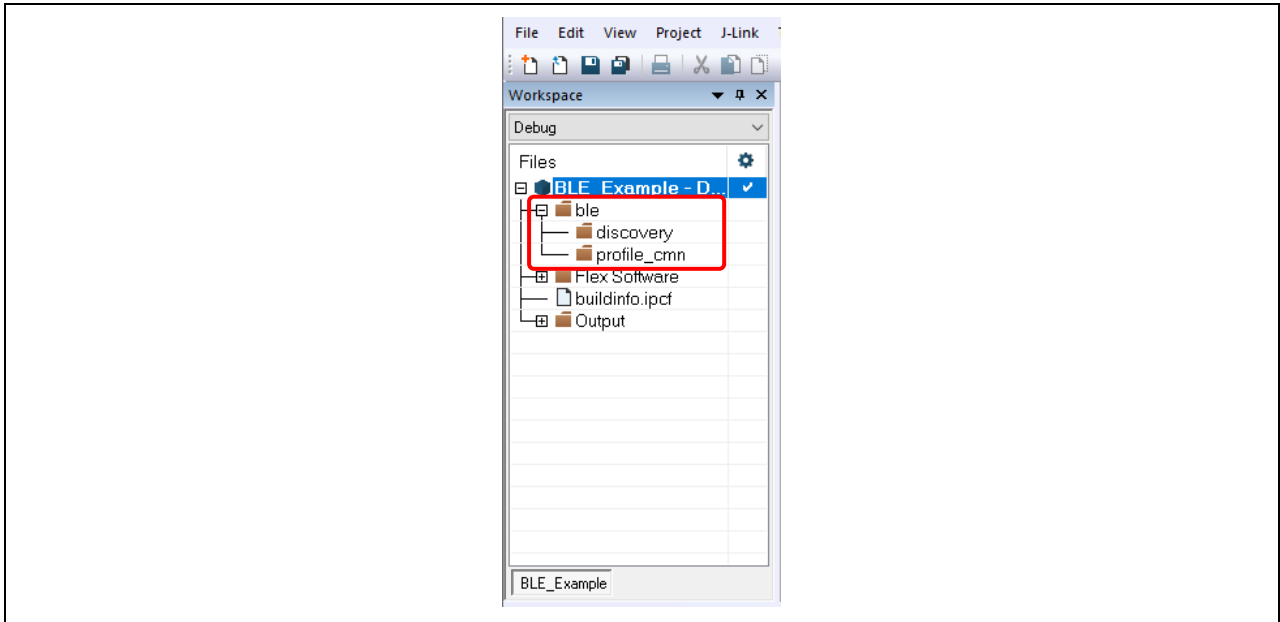


Figure 34. New Groups in the Project Tree

4. Right-click on **ble** group and select **Add > Add Files...** Select all the source files inside the **ble** folder and click **Open** to add them to the project.

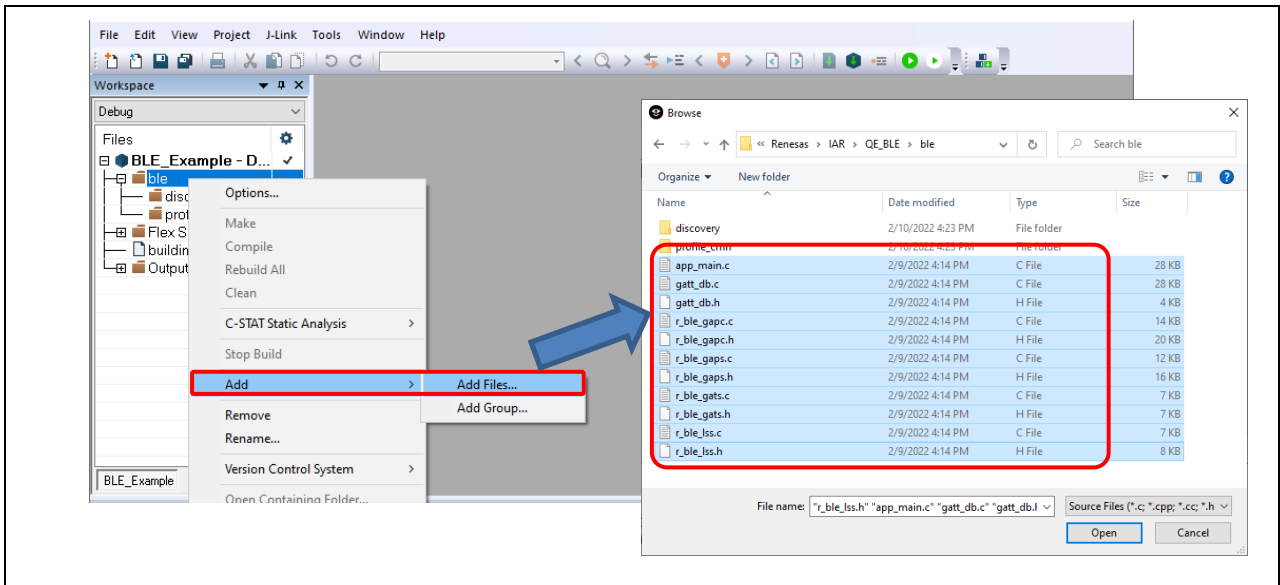


Figure 35. Add Source Files for ble Group

- Do the same to add source files to **discovery** and **profile_cmh** group. Finally, the project should look like this.

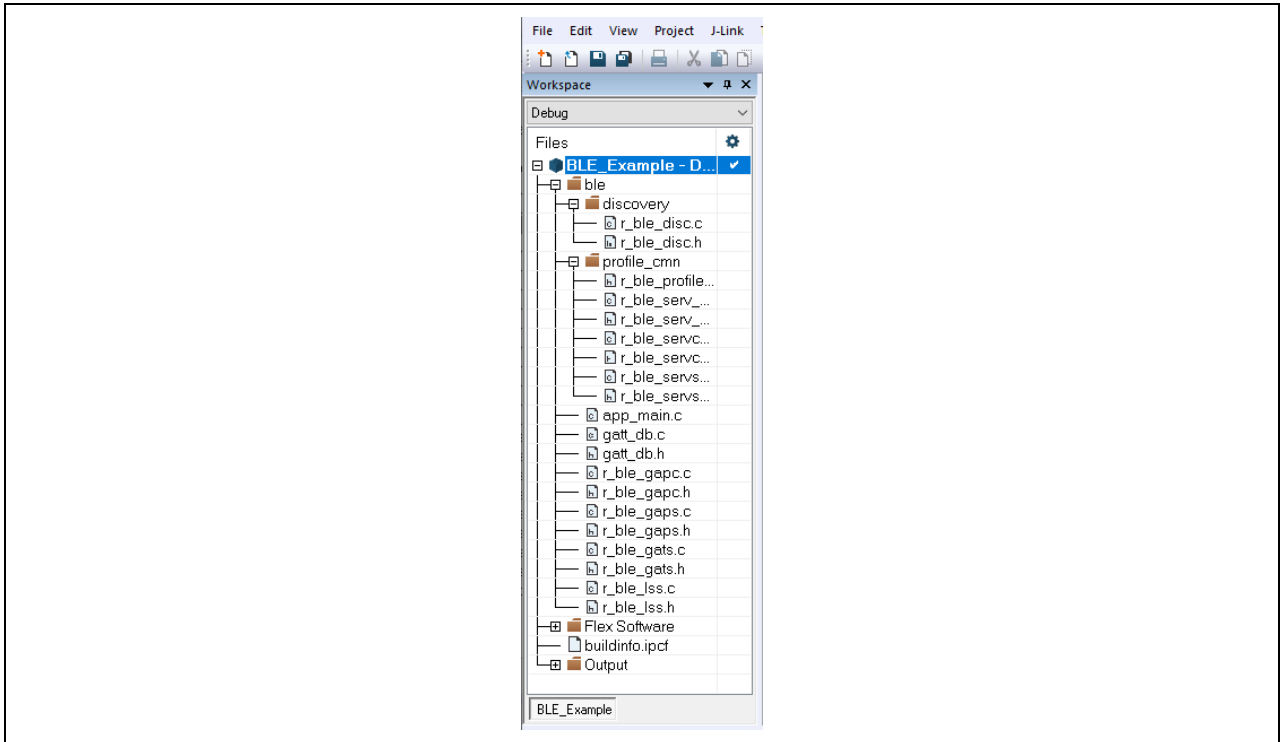


Figure 36. All Source Files have been Added

- Right click on project name and select **Options....** In the **Options** dialog, select **C/C++ Compiler > Preprocessor**. Click on the [...] button to add include directory.

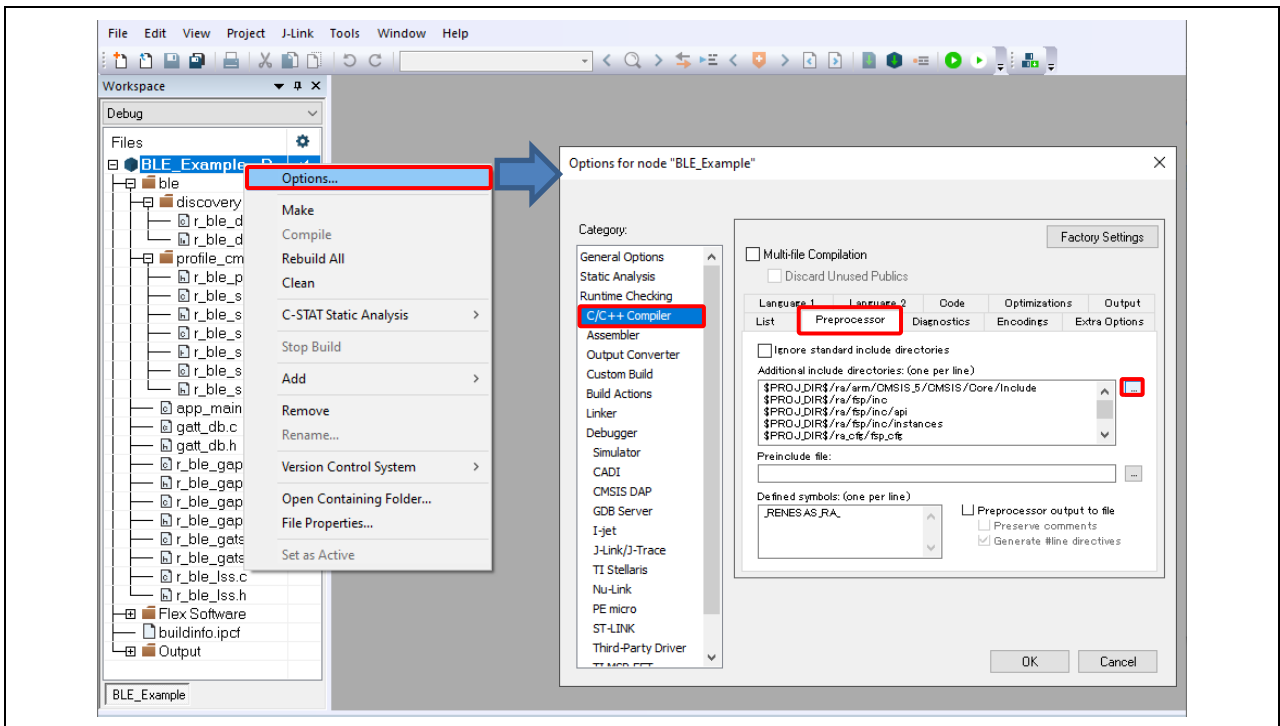


Figure 37. Open Project Option

- Click on the empty row and add the **ble** folder to the list of include directories. The triangle button can be used to change the absolute path to relative path. Click **OK** to close the dialog.

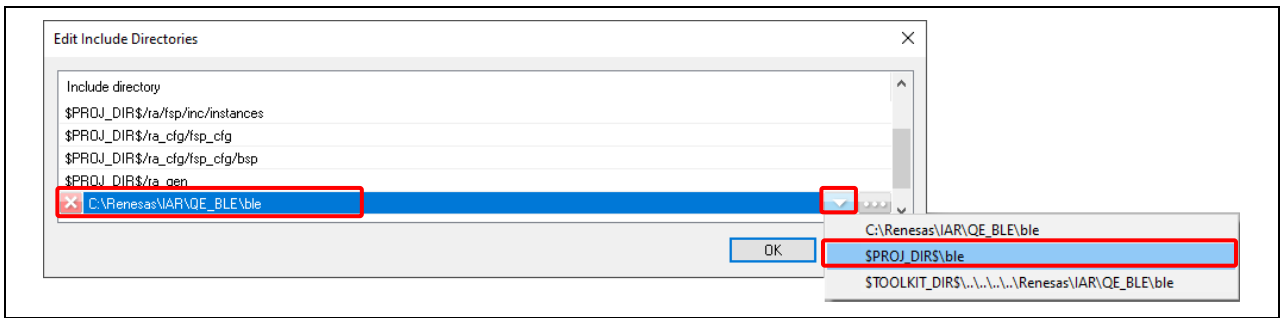


Figure 38. Add ble to List of Include Directories

- Right-click on the project and select **Rebuild All**. The project should be built without error.

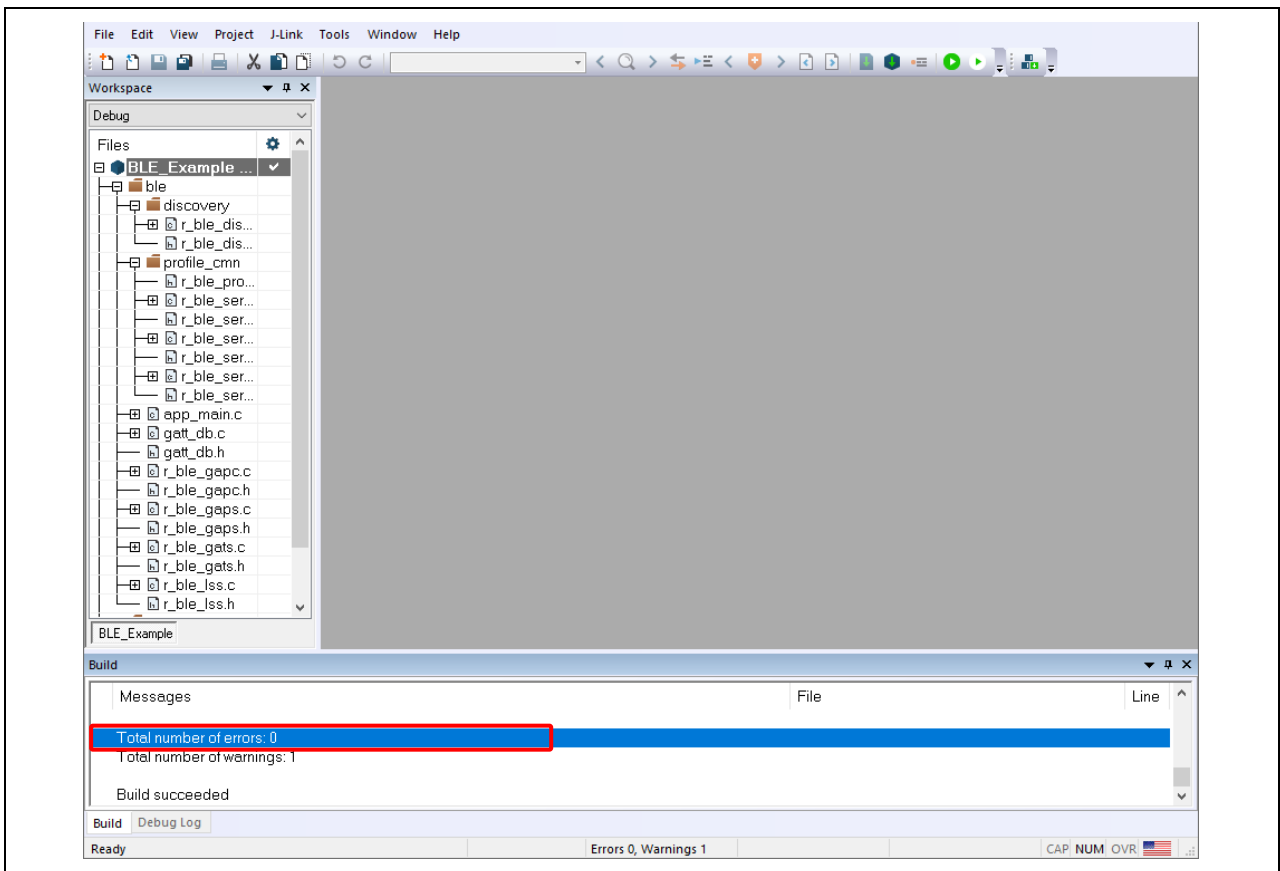


Figure 39. Build Successfully

Website and Support

Visit the following vanity URLs to learn about key elements of the RA family, download components and related documentation, and get support.

RA Product Information	www.renesas.com/ra
RA Product Support Forum	www.renesas.com/ra/forum
RA Flexible Software Package	www.renesas.com/FSP
Renesas Support	www.renesas.com/support

Revision History

Rev.	Date	Description	
		Page	Summary
1.00	Feb.26.21	—	First release document
1.10	Feb.18.22	1	Update to Operating Environment
		—	Changed version FSP to v3.5.0
		—	Changed version QE for BLE V1.4.0
		12	3.8. Added Smart Configurator Close
		19	5.1. Added ble folder copy operation

General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity.

Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (Max.) and V_{IH} (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (Max.) and V_{IH} (Min.).

7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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